Recent Papers by IBM Authors

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• *Book abstract*

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This book is a bibliography of over 4400 references of the world literature on MOSFET technologies and VLSI. The volume is broken down into three chapters: technologies, properties and characterization, and dielectric thin films. A detailed subject index appears at the end of the book. Every chapter cites books and review articles for beginners and graduate students in the field. Novel technologies, such as silicide-gate FETs and VLSI, are highlighted.